











SN54LV02A, SN74LV02A

SCLS390K - APRIL 1998 - REVISED FEBRUARY 2015

SNx4LV02A Quadruple 2-Input Positive-NOR Gates

Features

- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 6.5 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) $> 2.3 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support Mixed-Mode Voltage Operation on All **Ports**
- I_{off} Supports Live insertion, Partial Power Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model
 - 200-V Machine Model
 - 1000-V Charged-Device Model

2 Applications

- Handset: Smartphone
- **Network Switch**
- Health & Fitness / Wearables
- **PDAs**
- TV (LCD)
- Power Infrastructure

3 Description

The SNx4LV02A devices are quadruple 2-input positive-NOR gates designed for 2-V to 5.5-V V_{CC} operation.

The SNx4LV02A devices perform the Boolean function $Y = \overline{A + B}$ or $Y = \overline{A} \bullet \overline{B}$ in positive logic.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	VQFN (14)	3.50 mm x 3.50 mm
	SOIC (14)	8.65 mm x 3.91 mm
SNx4LV02A	SOP (14)	10.30 mm x 5.30 mm
	SSOP (14)	6.20 mm x 5.30 mm
	TSSOP (14)	5.00 mm x 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic





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5 Revision History

Changes from Revision I (April 2005) to Revision K

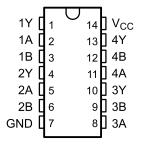
Page

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and

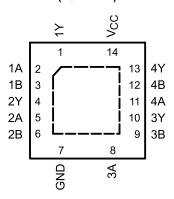


6 Pin Configuration and Functions

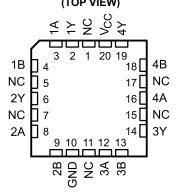
SN54LV02A ... J OR W PACKAGE SN74LV02A ... D, DB, DGV, NS, OR PW PACKAGE (TOP VIEW)



SN74LV02A ... RGY PACKAGE (TOP VIEW)



SN54LV02A ... FK PACKAGE (TOP VIEW)



NC - No internal Connection

Pin Functions

		= ==:	
	PIN	TYPE	DESCRIPTION
NO.	NAME	ITPE	DESCRIPTION
1	1Y	0	1Y output
2	1A	I	1A input
3	1B	I	1B input
4	2Y	0	2Y output
5	2A	I	2A input
6	2B	I	2B input
7	GND	_	GND
8	3A	I	3A input
9	3B	I	3B input
10	3Y	0	3Y output
11	4A	I	4A input
12	4B	1	4B input
13	4Y	0	4Y output
14	V _{cc}	_	Vcc

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high-impe	dance or power-off state (2)	-0.5	7	V
Vo	Output voltage range (2)(3)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GND	•		±50	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±1500	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	±2000	V

¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ This value is limited to 5.5-V maximum.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN54LV	02A ⁽²⁾	SN74LV	/02A	
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
. ,	The first of the second	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} × 0.7		V _{CC} × 0.7		.,
V _{IH}	High-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	V _{CC} × 0.7		$V_{CC} \times 0.7$		V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	V _{CC} × 0.7		$V_{CC} \times 0.7$		
		V _{CC} = 2 V		0.5		0.5	
.,	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
V _{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	
VI	Input voltage		0	5.5	0	5.5	V
Vo	Output voltage		0	5.5	0	5.5	V
		V _{CC} = 2 V		- 50		-50	μΑ
	High lavel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-2		-2	
Іон	High-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-6		-6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-12		-12	
		V _{CC} = 2 V		50		50	
ı	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	mA
ІІН	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		6		6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		12		12	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		200		200	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		100		100	ns/V
		V _{CC} = 4.5 V to 5.5 V		20		20	
T _A	Operating free-air temperature		-55	125	-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

7.4 Thermal Information

				SN7	74LV02A			
	THERMAL METRIC ⁽¹⁾	D	DB	DGV	NS	PW	RGY	UNIT
		14 PINS						
$R_{\theta JA}$	Junction-to-ambient thermal resistance	97.5	109.5	133.3	92.2	125.1	59.0	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	58.7	62.1	55.6	49.8	53.7	72.5	
$R_{\theta JB}$	Junction-to-board thermal resistance	51.8	56.9	66.3	51.0	66.9	35.0	
ΨЈТ	Junction-to-top characterization parameter	22.6	22.6	7.8	15.7	7.6	3.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	51.6	56.3	56.6	50.6	66.3	35.1	
R ₀ JC(bot)		-	-	-	-	-	15.4	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

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⁽²⁾ Product Preview.



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	SN5	4LV02A ⁽¹)	-40°C to SN74L\		-40°C to SN74LV		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	I _{OL} = -50 μA	2 V to 5.5 V	V _{CC} – 0.1			V _{CC} – 0.1		V _{CC} – 0.1		
V _{OH}	$I_{OL} = -2 \text{ mA}$	2.3 V	2			2		2		
	$I_{OL} = -6 \text{ mA}$	3 V	2.48			2.48		2.48		
	$I_{OL} = -12 \text{ mA}$	4.5 V	3.8			3.8		3.8		
	I _{OL} = 50 μA	2 V to 5.5 V			0.1		0.1		0.1	
V _{OL}	I _{OL} = 2 mA	2.3 V			0.4		0.4		0.4	V
	I _{OL} = 6 mA	3 V			0.44		0.44		0.44	
	I _{OL} = 12 mA	4.5 V			0.55		0.55		0.55	
I _I	V _I = 5.5 V or GND	0 to 5.5 V			±1		±1		±1	μΑ
I _{cc}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5			20		20		20	μΑ
I _{off}	V_I or $V_O = 0$ to 5.5 V	0			5		5		5	μΑ
C _i	$V_I = V_{CC}$ or GND	3.3 V		1.6		1.	.6	1.0	6	pF

⁽¹⁾ Product Preview.

7.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE		T _A = 25°	С	SN54L	.V02A		to 85°C LV02A	-40°C to SN74L\		UNIT
	(INPOT)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	A 0 * D	V	$C_L = 15 pF$		8.3(1)	12.4 ⁽¹⁾	1 ⁽¹⁾	15 ⁽¹⁾	1	15	1	17.5	
^l pd	A or B	r	$C_L = 50 pF$		11 ⁽¹⁾	16.1 ⁽¹⁾	1	19	1	19	1	21.5	ns

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE		T _A = 25°0	C	SN54L	V02A	-40°C t SN74L	o 85°C -V02A	-40°C to SN74L\		UNIT
	(INFUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	A or D	V	C _L = 15 pF		5.6 ⁽¹⁾	7.9 ⁽¹⁾	1 ⁽¹⁾	9.5 ⁽¹⁾	1	9.5	1	11.5	
τ _{pd}	A or B	Ť	C _L = 50 pF		7.6 ⁽¹⁾	11.4 ⁽¹⁾	1	13	1	13	1	15	ns

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T,	_A = 25°C	;	SN54L	V02A	-40°C t SN74L		-40°C to SN74L		UNIT
	(INFUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
4	A or B	V	C _L = 15 pF		3.9 ⁽¹⁾	5.5 ⁽¹⁾	1 (1)	6.5 ⁽¹⁾	1	6.5	1	8	20
ι _{pd}	AUID	Ť	C _L = 50 pF		5.3 ⁽¹⁾	7.5 ⁽¹⁾	1	8.5	1	8.5	1	10	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



7.9 Noise Characteristics(1)

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$

	PARAMETER	SN	74LV02A		UNIT
	PARAMETER	MIN	TYP	MAX	UNII
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.2	8.0	V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}		-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.2		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

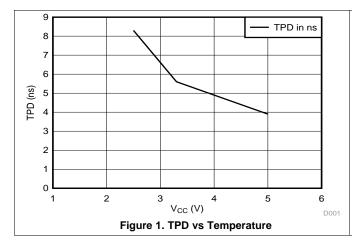
⁽¹⁾ Characteristics are for surface-mount packages only.

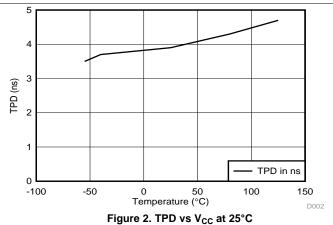
7.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST C	ONDITIONS	V _{CC}	TYP	UNIT
_	Dawar discipation conscitance	C _L = 50 pF,	f 40 MHz	3.3 V	8.9	~F
C _{pd}	Power dissipation capacitance		f = 10 MHz	5 V	3	pF

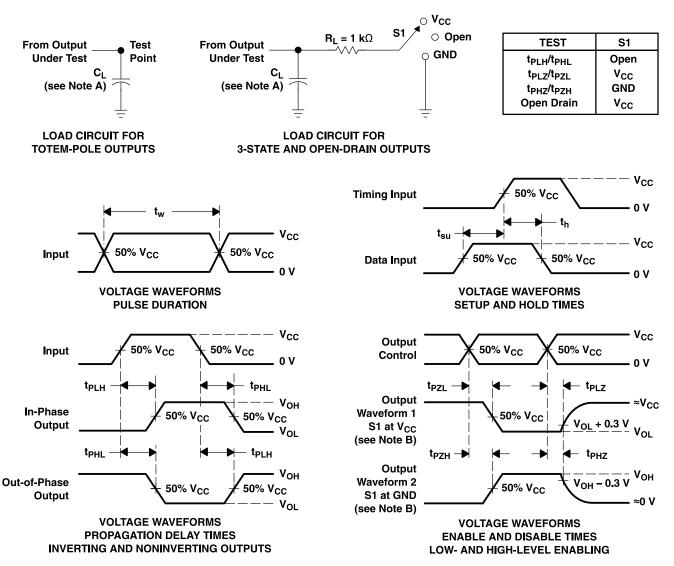
7.11 Typical Characteristics







8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_f \leq$ 3 ns. $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



9 Detailed Description

9.1 Overview

The SN74LV02A devices are quadruple 2-input positive-NOR gates designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV02A devices perform the Boolean function $Y = \overline{A} + \overline{B}$ or $Y = \overline{A} \bullet \overline{B}$ in positive logic.

These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

9.2 Functional Block Diagram



Figure 4. Logic Diagram (Positive Logic)

9.3 Feature Description

- Wide operating voltage range
 - Operates from 2 V to 5.5 V
- Allows down voltage translation
 - Inputs accept voltages to 5.5 V
- I_{off} feature allows voltages on the inputs and outputs when V_{CC} is 0 V

9.4 Device Functional Modes

Table 1. Function Table (Each Gate)

INF	OUTPUT			
Α	A B			
Н	Χ	Г		
X	Н	L		
L	L	Н		

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LV02A is a Low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages to 5.5~V at any valid V_{CC} making it Ideal for down translation.

10.2 Typical Application

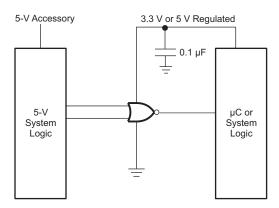


Figure 5. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

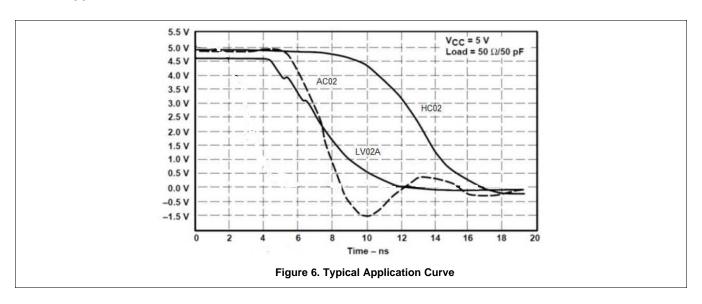
10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - For specified High and low levels, see V_{IH} and V_{IL} in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ f capacitor is recommended and if there are multiple V_{CC} terminals then .01 μ f or .022 μ f capacitor is recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ f and 1 μ f capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

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12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient. It is generally OK to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O's so they also cannot float when disabled.

12.2 Layout Example

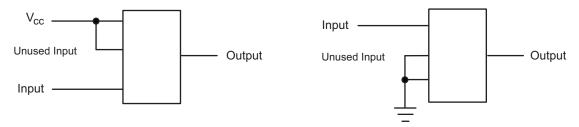


Figure 7. Layout Diagram

13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LV02A	Click here	Click here	Click here	Click here	Click here	

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN54LV02A SN74LV02A

www.ti.com

24-Jul-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SN74LV02AD	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 125	LV02A
SN74LV02ADBR	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADBR.A	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADBRE4	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADGVR	Active	Production	TVSOP (DGV) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADGVR.A	Active	Production	TVSOP (DGV) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ADR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ANSR	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV02A
SN74LV02ANSR.A	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV02A
SN74LV02APW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-40 to 125	LV02A
SN74LV02APWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02APWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02APWR.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02APWRG4.A	Active	Production	TSSOP (PW) 14	2000 null	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02APWRG4.A	Active	Production	TSSOP (PW) 14	2000 null	No	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02APWT	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-40 to 125	LV02A
SN74LV02ARGYR	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ARGYR.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ARGYRG4	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A
SN74LV02ARGYRG4.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV02A

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV02ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV02ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV02ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV02ANSR	SOP	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74LV02APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV02ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
SN74LV02ARGYRG4	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV02ADBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74LV02ADGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74LV02ADR	SOIC	D	14	2500	353.0	353.0	32.0
SN74LV02ANSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74LV02APWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LV02ARGYR	VQFN	RGY	14	3000	360.0	360.0	36.0
SN74LV02ARGYRG4	VQFN	RGY	14	3000	360.0	360.0	36.0

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

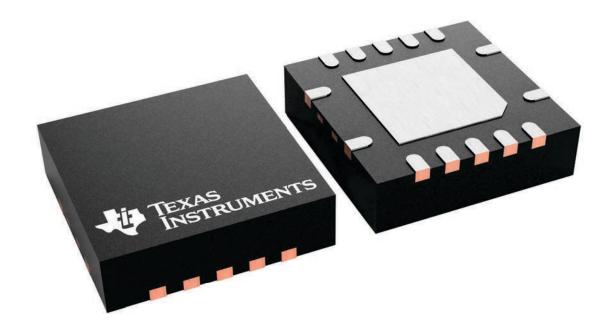
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



3.5 x 3.5, 0.5 mm pitch

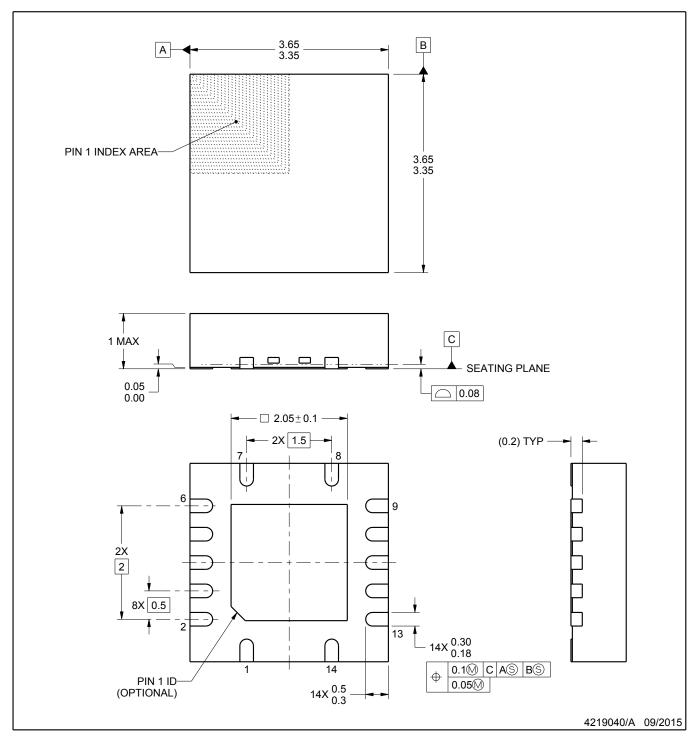
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD

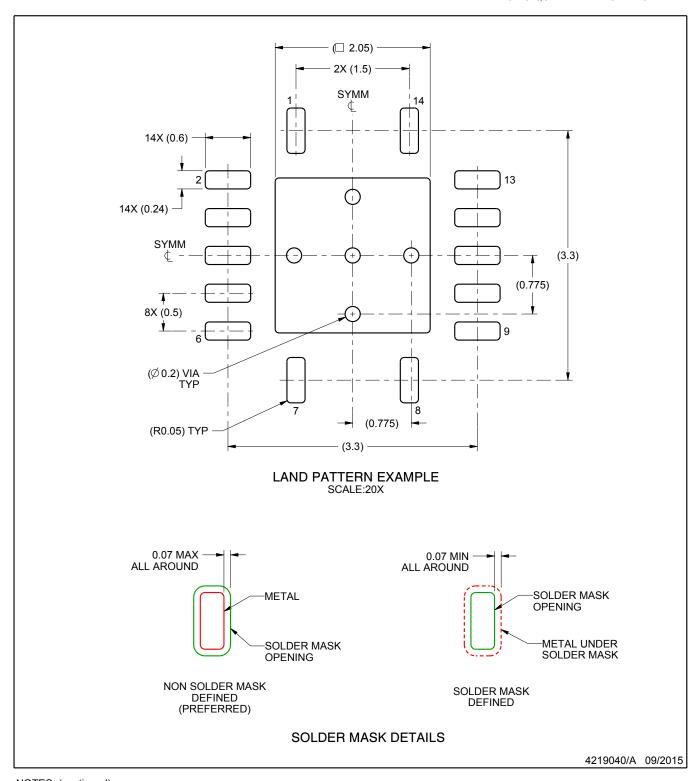


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

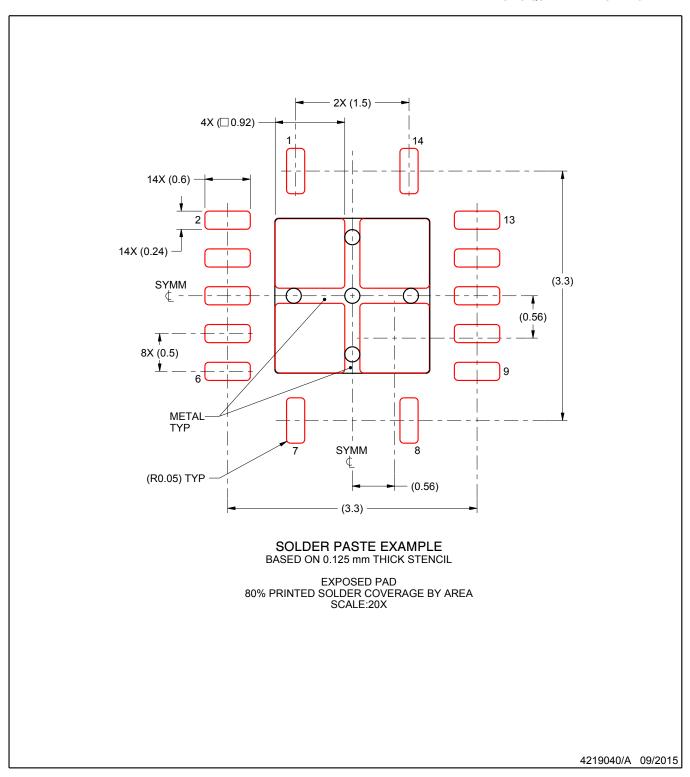


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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